

RELIABILITY REPORT
FOR
MAX14975ETG+T
PLASTIC ENCAPSULATED DEVICES

September 2, 2013

MAXIM INTEGRATED

160 RIO ROBLES
SAN JOSE, CA 95134

Approved by
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Conclusion

The MAX14975ETG+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAX14975 dual SuperSpeed USB 3.0 equalizer/redriver utilizes programmable input equalization and output deemphasis to reduce deterministic jitter and restore signal loss caused by circuit-board or signal-cable losses, and allows optimal placement of key SuperSpeed USB 3.0 components and longer circuit-board traces or cables. The device features advanced power management with receiver detection and explicit support for USB 3.0 low-frequency periodic signals (LFPS).

The device is available in a small, 24-pin (4.0mm x 4.0mm) TQFN package with flow-through traces for optimal layout and minimal space requirements. The device is specified over the -40°C to +85°C extended operating temperature range.

II. Manufacturing Information

A. Description/Function:	Dual SuperSpeed USB 3.0 Equalizer/Redriver with Extended Temperature Operation
B. Process:	MB3
C. Number of Device Transistors:	15225
D. Fabrication Location:	USA
E. Assembly Location:	China, Taiwan and Thailand
F. Date of Initial Production:	March 29, 2013

III. Packaging Information

A. Package Type:	24-pin TQFN 4x4
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-4512
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	48°C/W
K. Single Layer Theta Jc:	3°C/W
L. Multi Layer Theta Ja:	36°C/W
M. Multi Layer Theta Jc:	3°C/W

IV. Die Information

A. Dimensions:	53.1496X68.1102 mils
B. Passivation:	BCB
C. Interconnect:	Al with top layer 100% Cu
D. Backside Metallization:	None
E. Minimum Metal Width:	0.23 microns as drawn
F. Minimum Metal Spacing:	0.23 microns as drawn
G. Bondpad Dimensions:	
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

- A. Quality Assurance Contacts: Richard Aburano (Manager, Reliability Engineering)
Don Lipps (Manager, Reliability Engineering)
Bryan Preeshl (Vice President of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 78 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 14.1 \times 10^{-9}$$

$$\lambda = 14.1 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the MB3 Process results in a FIT Rate of 0.08 @ 25C and 1.33 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot S10ZAQ001C, D/C 1114)

The AK12-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/- 2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/- 250mA and overvoltage per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results

MAX14975ETG+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	78	0	S1OZAQ001C, D/C 1114

Note 1: Life Test Data may represent plastic DIP qualification lots.